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1N5817 THRU 1N5819

Features

- Guard Ring Protection
- Low Forward Voltage
- Low Power Loss For High Efficiency
- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level 1
- Lead Free Finish/RoHS Compliant (Note1)

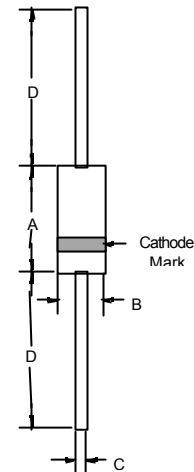
1 Amp Schottky Barrier Rectifier 20 to 40 Volts

Maximum Ratings

- Operating Temperature: -55°C to +125°C
- Storage Temperature: -55°C to +125°C
- Maximum Thermal Resistance; 80°C/W Junction To Ambient

Part Number	Maximum Recurrent Peak Reverse Voltage	Maximum RMS Voltage	Maximum DC Blocking Voltage
1N5817	20V	14V	20V
1N5818	30V	21V	30V
1N5819	40V	28V	40V

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Electrical Characteristics @ 25°C Unless Otherwise Specified

Average Forward Current	$I_{F(AV)}$	1.0A	$T_A = 90^\circ\text{C}$
Peak Forward Surge Current	I_{FSM}	25A	8.3ms, half sine
Maximum Instantaneous Forward Voltage	V_F	.45V	$I_{FM} = 1.0\text{A};$ $T_J = 25^\circ\text{C}^*$
1N5817		.55V	
1N5818		.60V	
Maximum DC Reverse Current At Rated DC Blocking Voltage	I_R	1.0mA	$T_J = 25^\circ\text{C}$ $T_J = 100^\circ\text{C}$
		10mA	
Typical Junction Capacitance	C_j	110pF	Measured at 1.0MHz, $V_R=4.0\text{V}$

DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	.166	.205	4.10	5.20	
B	.080	.107	2.00	2.70	
C	.028	.034	.70	.90	
D	1.000	---	25.40	---	

*Pulse test: Pulse width 300 μsec , Duty cycle 2%

Note: 1. High Temperature Solder Exemption Applied, see EU Directive Annex 7.

1N5817 thru 1N5819

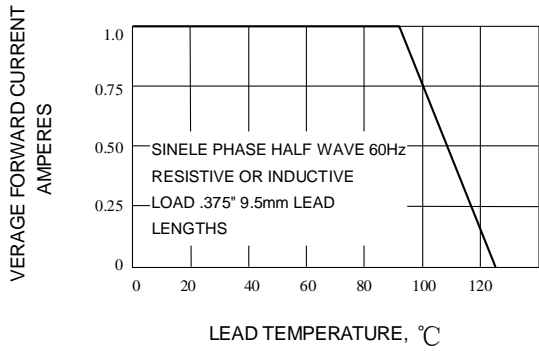


Fig. 1-FORWARD CURRENT DERATING CURVEE

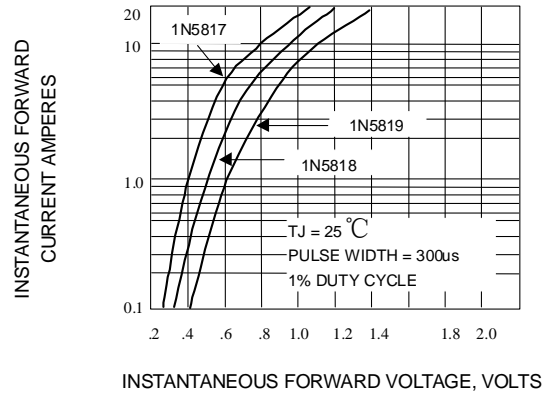


Fig. 2-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

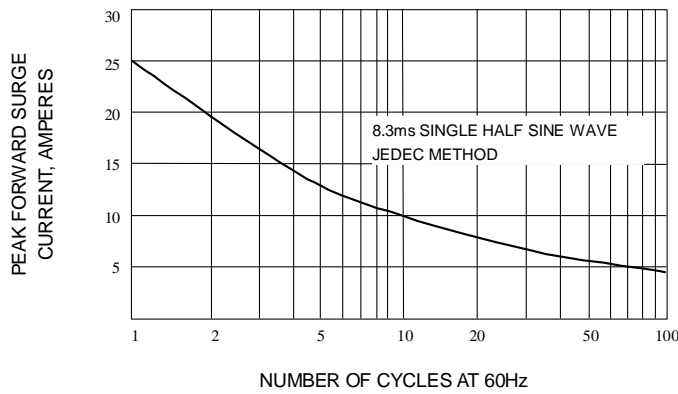


Fig. 3-MAXIMUM NON-REPETITIVE SURGE CURRENT

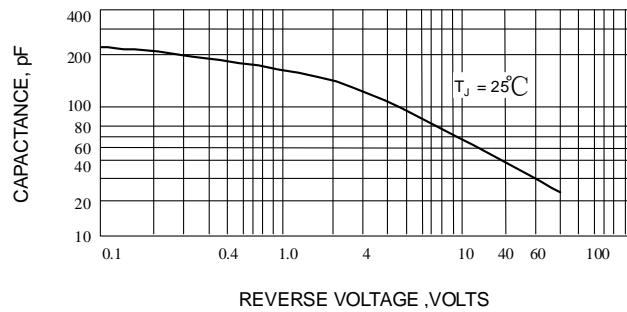


Fig. 4-TYPICAL JUNCTION CAPACITANCE